



SINGLE PHASE SILICON BRIDGE RECTIFIER

VOLTAGE RANGE: 50 - 1000V

CURRENT: 3.0 A

Features

- Diffused Junction
- High Current Capability
- High Case Dielectric Strength
- High Surge Current Capability
- Ideal for Printed Circuit Board Application
- Plastic Material has Underwriters Laboratory Flammability Classification 94V-O

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Marked on Body
- Weight: 3.8 grams (approx.)
- Mounting Position: Through Hole for #6 Screw
- Mounting Torque: 5.0 Inch-pounds Maximum
- Marking: Type Number







Dimensions in inches and (milimeters)

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	KBPC 3005	KBPC 301	KBPC 302	KBPC 304	KBPC 306	KBPC 308	KBPC 310	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) $@T_c = 50^{\circ}C$	lo	3.0							А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	50							А
Forward Voltage per leg @l _F = 1.5A	VFM	1.1						V	
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 125^{\circ}C$	IR	5.0 500						μA	
I ² t Rating for Fusing (t<8.3ms) (Note 2)	l ² t	10					A ² s		
Typical Junction Capacitance (Note 3)	Cj	25				pF			
Typical Thermal Resistance per leg (Note 1)	R⊕JC	10					°C/W		
Operating and Storage Temperature Range	Тj, Tsтg	-65 to +125					°C		

Note: 1. Mounted on metal chassis.

2. Non-repetitive, for t > 1ms and < 8.3ms.

3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.



